



MMBT3906T

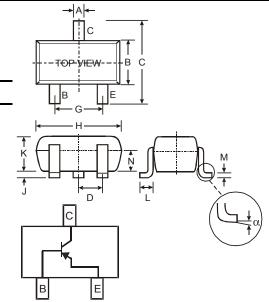
PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary NPN Type Available (MMBT3904T)
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-523
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Terminal Connections: See Diagram
- Marking Information: 3N, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.002 grams (approximate)



SOT-523									
Dim	Min	Max	Тур						
Α	0.15	0.30	0.22						
В	0.75	0.85	0.80						
С	1.45	1.75	1.60						
D		_	0.50						
G	0.90	1.10	1.00						
Н	1.50	1.70	1.60						
J	J 0.00		0.05						
K	0.60	0.80	0.75						
L	L 0.10		0.22						
М	0.10	0.20	0.12						
N	N 0.45		0.50						
α	0°	8°	_						
All Dimensions in mm									

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage		V _{CBO}	-40	V
Collector-Emitter Voltage		V _{CEO}	-40	V
Emitter-Base Voltage		V_{EBO}	-5.0	V
Collector Current - Continuous		Ic	-200	mA
Power Dissipation	(Note 1)	P_d	150	mW
Thermal Resistance, Junction to Ambient	(Note 1)	$R_{ hetaJA}$	833	°C/W
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C

Notes:

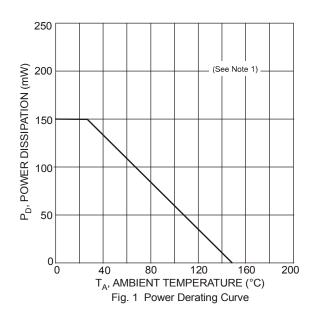
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

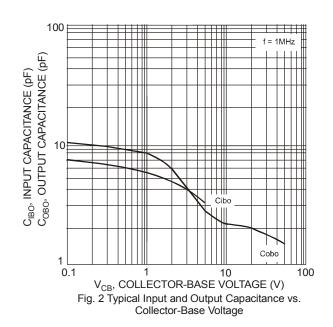


Electrical Characteristics @TA = 25°C unless otherwise specified

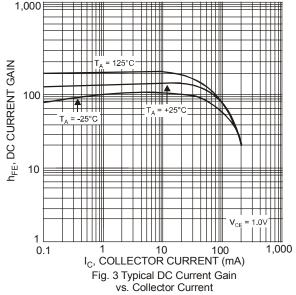
Characteristic	Symbol Min		Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 5)							
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	_	V	$I_C = -10\mu A, I_E = 0$		
Collector-Emitter Breakdown Voltage		-40	_	V	$I_C = -1.0 \text{mA}, I_B = 0$		
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	_	V	$I_E = -10\mu A$, $I_C = 0$		
Collector Cutoff Current	I _{CEX}	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$		
Base Cutoff Current	I _{BL}	_	-50	nA	V _{CE} = -30V, V _{EB(OFF)} = -3.0V		
ON CHARACTERISTICS (Note 5)							
DC Current Gain	h _{FE}	60 80 100 60 30	 300 	_	$\begin{split} I_C &= -100 \mu A, \ V_{CE} = -1.0 V \\ I_C &= -1.0 m A, \ V_{CE} = -1.0 V \\ I_C &= -10 m A, \ V_{CE} = -1.0 V \\ I_C &= -50 m A, \ V_{CE} = -1.0 V \\ I_C &= -100 m A, \ V_{CE} = -1.0 V \end{split}$		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.25 -0.40	V	$I_C = -10$ mA, $I_B = -1.0$ mA $I_C = -50$ mA, $I_B = -5.0$ mA		
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.65 —	-0.85 -0.95	V	I_C = -10mA, I_B = -1.0mA I_C = -50mA, I_B = -5.0mA		
Noise Figure		_	4.0	dB	V_{CE} = -5.0Vdc, I_{C} = 100 μ Adc, R_{S} = 1.0k Ω , f = 1.0kHz		
SMALL SIGNAL CHARACTERISTICS							
Output Capacitance	C _{obo}		4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$		
Input Capacitance	C _{ibo}		10	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$		
Input Impedance	h _{ie}	2.0	12	kΩ			
Voltage Feedback Ratio		0.1	10	x 10 ⁻⁴	$V_{CE} = 1.0V, I_{C} = 10mA,$		
Small Signal Current Gain	h _{fe}	100	400	_	f = 1.0kHz		
Output Admittance	h _{oe}	3.0	60	μS			
Current Gain-Bandwidth Product	f⊤	250		MHz	V _{CE} = -20V, I _C = -10mA, f = 100MHz		
SWITCHING CHARACTERISTICS							
Delay Time	t _d	_	35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$		
Rise Time	t _r	_	35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$		
Storage Time	ts		225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$		
Fall Time	t _f		75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$		

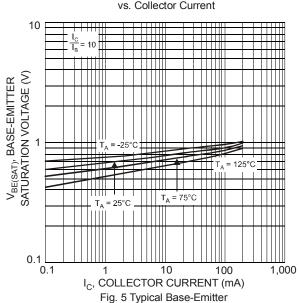
Notes: 5. Short duration pulse test used to minimize self-heating effect.











Saturation Voltage vs. Collector Current

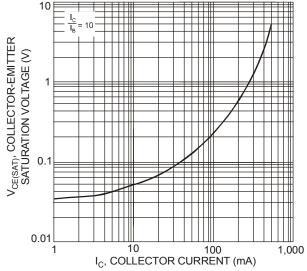


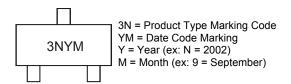
Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

Ordering Information (Note 6)

Device	Packaging	Shipping		
MMBT3906T-7-F	SOT-523	3000/Tape & Reel		

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



Date Code Key

Year	2002	2003	2004	2005	200	06 20	007	2008	2009	2010	2011	2012
Code	N	Р	R	S	Т		U	V	W	Х	Υ	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Ju	I Au	g Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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